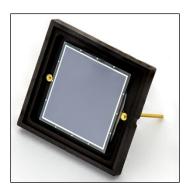


# Electron Detection 100 mm<sup>2</sup>



## **FEATURES**

- Ideal for Electron Detection
- Large Detection Area
- 100% Internal QE
- Protective Cover Plate<sup>3</sup>

## Electro-Optical Characteristics at 25 °C

Parameters	Test Conditions	Min	Тур	Max	Units
Active Area	100 mm x 100 mm		100		mm <sup>2</sup>
Responsivity	@ 254 mm, V <sub>R</sub> = 0 V	0.07	0.08	0.09	A/W
Shunt Resistance, Rsh	V <sub>B</sub> = ± 10 mV	20			M-ohm
Reverse Breakdown Voltage, $V_R$	I <sub>R</sub> = 1 μA	5	10		Volts
Capacitance, C	V <sub>R</sub> = 0 V		10	44	nF
Rise Time	$V_R$ = 0 V, $R_L$ = 50 $\Omega$			10	usec

## **Thermal Parameters**

Storage and Operating Temperature Range					
Ambient <sup>1</sup>	-10 ° to 40 °C				
Nitrogen or Vacuum	-20 °C to 80 °C				
Maximum Junction Temperature	70 °C				
Lead Soldering Temperature <sup>2</sup>	260 °C				

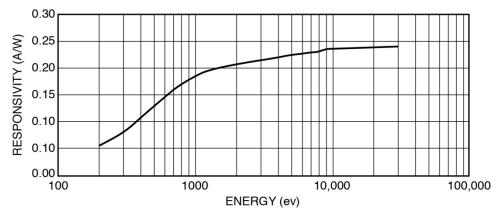
<sup>1</sup> Temperatures exceeding these parameters may create oxide growth on the active area. Over time responsivity to low energy radiation and wavelengths below 150 nm will be compromised.

<sup>2</sup> 0.080" from case for 10 seconds.

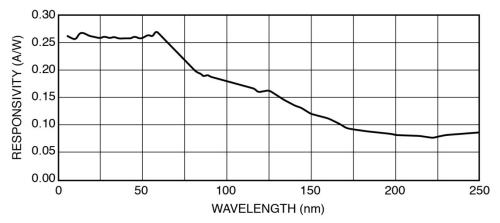
<sup>3</sup> Shipped with temporary cover to protect the photodiode and wire bonds. Review the Application Note, "Handling Precautions for AXUV, SXUV, and UVG Detectors", prior to removing cover.



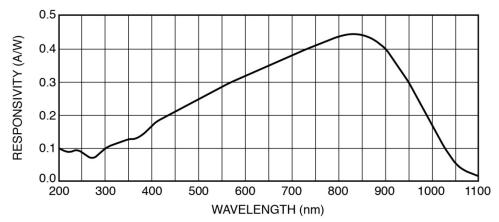
## **Typical Electron Response**



# **Typical EUV-UV Photon Response**



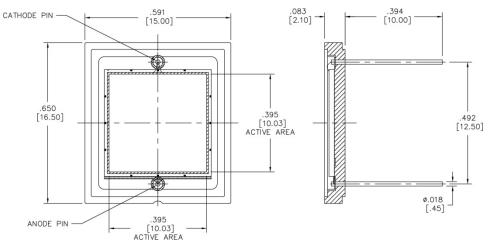
# Typical UV-VIS-NIR Photon Responsivity





**Electron Detection 100 mm<sup>2</sup>** 

#### **Package Information**



Dimensions are in inch [metric] units.

#### **Ordering Information**

ODD-AXU-010

Large Photodiode Ideal for Radiation Detection Shipped with Protective Cover



Specifications are subject to change without prior notice.